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SLPS255A – FEBRUARY 2010 – REVISED JULY 2010

30V, N-Channel NexFET[™] Power MOSFETs

Check for Samples: CSD17310Q5A

FEATURES

- Optimized for 5V Gate Drive
- Ultralow Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

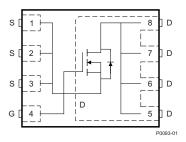
APPLICATIONS

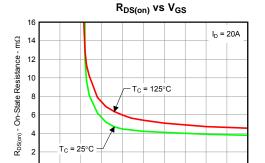
- Notebook Point of Load
- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems
- Optimized for Synchronous FET Applications

DESCRIPTION

The NexFET[™] power MOSFET has been designed to minimize losses in power conversion applications, and optimized for 5V gate drive applications.







V_{GS} - Gate-to-Source Voltage - V

PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage 30		V	
Qg	Gate Charge Total (4.5V)	8.9		nC
Q _{gd}	Gate Charge Gate to Drain	2.1		nC
		$V_{GS} = 3V$	5.7	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 4.5V$	4.5	mΩ
		$V_{GS} = 8V$	3.9	mΩ
V _{GS(th)}	Threshold Voltage	1.3		V

ORDERING INFORMATION

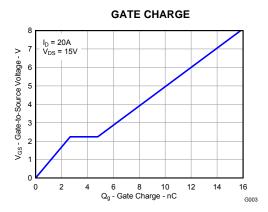
Device	Package	Media	Qty	Ship
CSD17310Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 2$	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	30	V
V_{GS}	Gate to Source Voltage	+10 /8	V
	Continuous Drain Current, $T_C = 25^{\circ}C$	100	А
ID	Continuous Drain Current ⁽¹⁾	21	А
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	134	А
PD	Power Dissipation ⁽¹⁾	3.1	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse $I_D = 58A$, L = 0.1mH, $R_G = 25\Omega$	168	mJ

(1) $R_{\theta JA} = 40^{\circ}$ C/W on 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration $\leq 300 \mu s$, duty cycle $\leq 2\%$



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XAS STRUMENTS

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	naracteristics					
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30			V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 24V$			1	μA
I _{GSS}	Gate to Source Leakage Current	V _{DS} = 0V, V _{GS} = +10/-8V			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.9	1.3	1.8	V
		V _{GS} = 3V, I _D = 20A		5.7	7.8	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V, I _D = 20A		4.5	5.9	mΩ
		V _{GS} = 8V, I _D = 20A		3.9	5.1	mΩ
9 _{fs}	Transconductance	V _{DS} = 15V, I _D = 20A		85		S
Dynamic	Characteristics	· · · · · · · · · · · · · · · · · · ·				
C _{iss}	Input Capacitance			1200	1560	pF
C _{oss}	Output Capacitance	V _{GS} = 0V, V _{DS} = 15V, f = 1MHz		630	820	pF
C _{rss}	Reverse Transfer Capacitance			59	77	pF
R _G	Series Gate Resistance			0.9	1.8	Ω
Qg	Gate Charge Total (4.5V)			8.9	11.6	nC
Q _{gd}	Gate Charge Gate to Drain			2.1		nC
Q _{gs}	Gate Charge Gate to Source	$V_{\rm DS} = 15 V, I_{\rm DS} = 20 A$		2.7		nC
Q _{g(th)}	Gate Charge at Vth			1.4		nC
Q _{oss}	Output Charge	V _{DS} = 12.8V, V _{GS} = 0V		15.9		nC
t _{d(on)}	Turn On Delay Time			6.5		ns
tr	Rise Time	V _{DS} = 15V, V _{GS} = 4.5V, I _{DS} = 20A,		11.6		ns
t _{d(off)}	Turn Off Delay Time	$R_{\rm G} = 2\Omega$		15		ns
t _f	Fall Time			5		ns
Diode Cl	haracteristics	· · ·				
V _{SD}	Diode Forward Voltage	$I_{SD} = 20A, V_{GS} = 0V$		0.85	1	V
Q _{rr}	Reverse Recovery Charge			21		nC
t _{rr}	Reverse Recovery Time	V _{DD} = 12.8V, I _F = 20A, di/dt = 300A/μs		22		ns

THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

	PARAMETER	MIN	TYP	MAX	UNIT
R_{\thetaJC}	Thermal Resistance Junction to Case ⁽¹⁾			1.9	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			51	°C/W

 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu. (1)

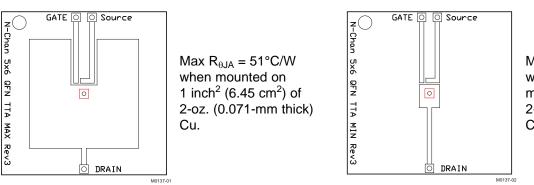
(2)



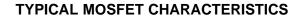
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Max $R_{\theta,JA} = 123^{\circ}C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.



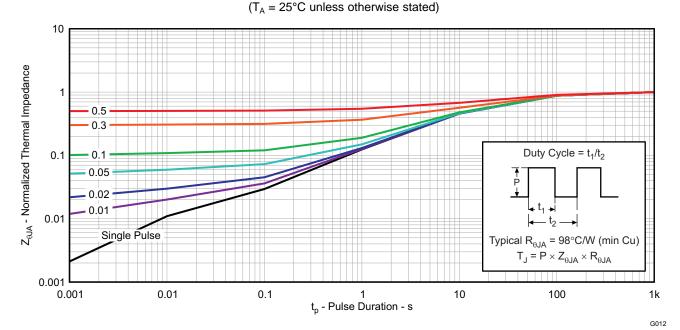


Figure 1. Transient Thermal Impedance

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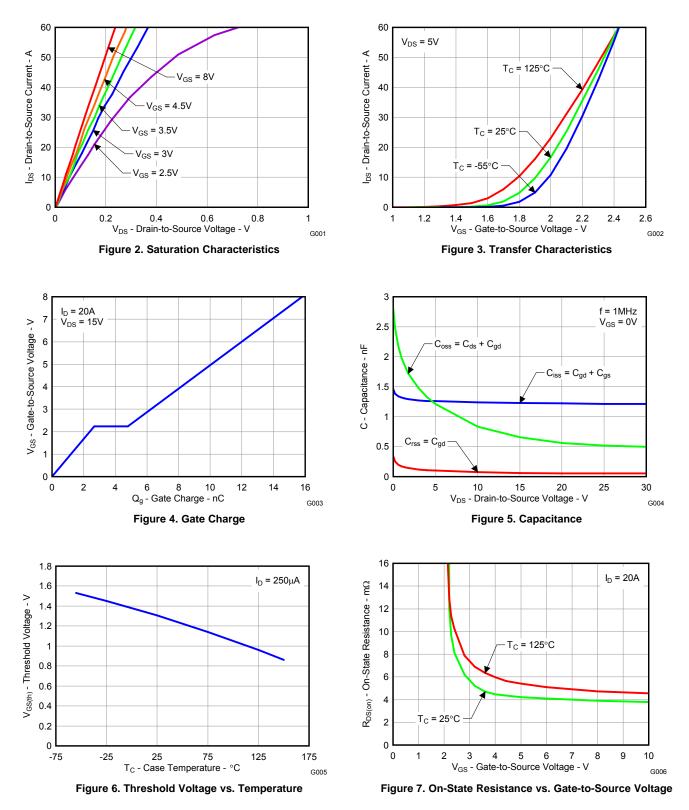
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ISTRUMENTS

FEXAS

TYPICAL MOSFET CHARACTERISTICS (continued)

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$





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TYPICAL MOSFET CHARACTERISTICS (continued)

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$

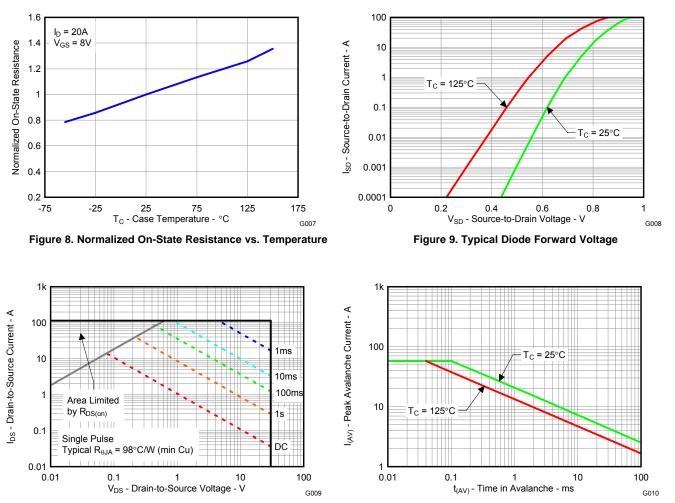
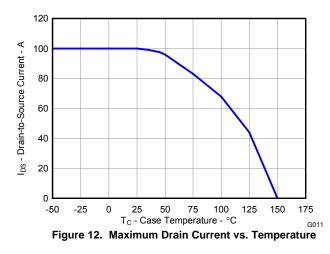




Figure 11. Single Pulse Unclamped Inductive Switching

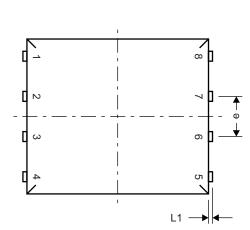


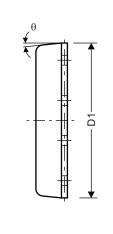
TEXAS INSTRUMENTS

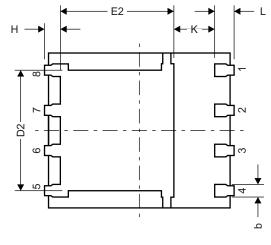
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MECHANICAL DATA

Q5A Package Dimensions



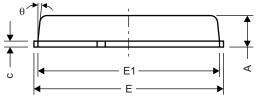




Top View

Side View

Bottom View



Front View

M0135-01

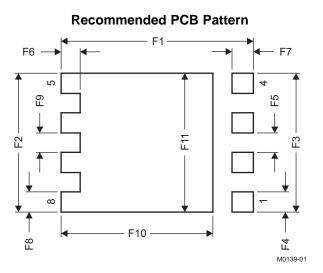
DIM		MILLIMETERS							
DIM	MIN	NOM	MAX						
A	0.90	1.00	1.10						
b	0.33	0.41	0.51						
С	0.20	0.25	0.34						
D1	4.80	4.90	5.00						
D2	3.61	3.81	4.02						
E	5.90	6.00	6.10						
E1	5.70	5.75	5.80						
E2	3.38	3.58	3.78						
е	1.17	1.27	1.37						
Н	0.41	0.56	0.71						
К	1.10								
L	0.51	0.61	0.71						
L1	0.06	0.13	0.20						
θ	0°		12°						



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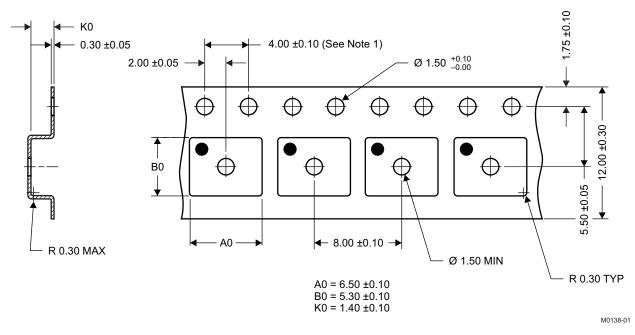
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DIM	MILLIM	ETERS	INCHES		
DIN	MIN	MAX	MIN	MAX	
F1	6.205	6.305	0.244	0.248	
F2	4.46	4.56	0.176	0.18	
F3	4.46	4.56	0.176	0.18	
F4	0.65	0.7	0.026	0.028	
F5	0.62	0.67	0.024	0.026	
F6	0.63	0.68	0.025	0.027	
F7	0.7	0.8	0.028	0.031	
F8	0.65	0.7	0.026	0.028	
F9	0.62	0.67	0.024	0.026	
F10	4.9	5	0.193	0.197	
F11	4.46	4.56	0.176	0.18	

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5A Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket

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REVISION HISTORY

Cł	nanges from Original (February 2010) to Revision A	Page
•	Updated the Q5A Package Dimensions table. DIM c MAX was 0.30, DIM D2 MAX was 3.96, DIM e MIN was blank MAX was blank, DIM H NOM was 0.51 MAX was 0.61	6
•	Deleted Note 6 from the Q5A Tape and Reel Information - "MSL1 260°C (IR and convection) PbF reflow compatible"	7
•	Deleted the Package Marking Information section	

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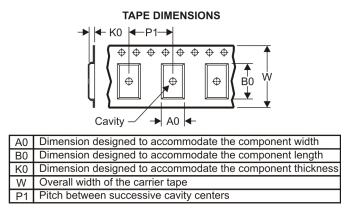
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD17310Q5A	SON	DQJ	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1
CSD17310Q5A	SON	DQJ	8	2500	330.2	12.4	6.5	5.3	1.4	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

20-May-2011



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD17310Q5A	SON	DQJ	8	2500	340.0	340.0	38.0
CSD17310Q5A	SON	DQJ	8	2500	347.0	342.0	55.0

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